A Pilgrim's Guide to Semiconductor Energy Bands

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Of course, the question of the moment is:

"Why do we care about this?"

The details of the band structure have become very important to modern nano-technology, even to the semiconductor industry. It is also important in understanding transport measurements.



Progress in Moore's Law Depends Upon Deep Understanding of the Material Properties





The NMOS device is *tensilely* strained to split the conduction bands and improve the mobility The PMOS device is compressively strained to warp the valence bands and improve the mobility





This knowledge is even more important for today's tri-gate devices (left) and the future nanowire devices (right)





IBM



Data from Prof. Jon Bird's group (Buffalo) on WSe₂ monolayer.

This behavior goes away if the material is annealed (heated) for a long period of time.











NDC in strained WS₂ (with T-K ~ 115 meV; 1% strain)







Discover how easy it is to grasp the basics of band theory

Band Theory FOR DUMMIES

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Si, and most semiconductors, are covalently bonded with their 4 valence electrons.

The outer electrons are 1 s state and 3 p states, which form hybrids.

The hybrids form a tetrahedral, which is due to the repulsion between the hybrids.



Naturally, there are two 'Gods' of band theory:



Walter Kohn



John C. Slater





John Slater went to Cambridge and Copenhagen after finishing his Ph.D. He remarked about Bohr's

"...hand-waving approach to anything. I had supposed, when I went to Copenhagen, that although Bohr's papers looked like hand-waving, they were just covering up all the mathematics and careful thought that had gone on underneath. The thing I convinced myself of after a month, was that there was nothing underneath. It was all just hand waving."

He returned to Harvard, then took over MIT's physics department. In the subsequent decades, he wrote the *Bible*: 5 books on quantum theory of atoms, molecules, and solids.





Walter Kohn came later. But, it was he who received the Nobel prize in 1998 for developing modern density functional theory.

An Austrian, he left in 1938 for England, then Canada, and finally the US. Associated with Bell Labs as well as his university appointments, he delved heavily into condensed matter physics, and computational approaches to the theories of electronic structure.

Kohn is responsible for DFT. He (and Hohenberg) showed that the many-body interactions could be represented by a linear response functional of the local density (hence the D in DFT).

We will find that this is a mean-field theory and needs some corrections.



To do band structure, we really need two things: We need to know the atoms, and we need to know the crystal structure.



Nearly all tetrahedrally coordinated semiconductors have the face-centered cubic cell (which actually includes eight unit cells).

There are two atoms per unit cell in this structure.

These two atoms define the "structure factor."



To do band structure, we really want to ignore the core electrons of the inner shells of the atoms---e.g., deal only with the bonding valence electrons. To do this, we use pseudo-potentials.

$$W(r) = V(r) + \sum_{t,j} \left(E - E_{t,j} \right) |t,j\rangle \langle t,j|.$$

Core energies and wave functions which are taken out of the real potential.

real atomic-potential

Pseudo-potential





This produces a smoothed potential and wave function which is far easier to handle, as we can avoid rapid oscillations and divergences (both of which multiply computing time). To this, we add an exchange-correlation potential, which is a functional of the density; for example the Dirac exchange and Perdew-Zunger correlation:

$$V_{XC}(\rho) = -\frac{3}{4} \left(\frac{3}{\pi}\right)^{1/3} \rho^{1/3} + \frac{\gamma}{1 + \beta_1 \sqrt{r_s} + \beta_2 r_s} , \quad r_s > 1$$
$$r_s = \left(\frac{3}{4\pi\rho}\right)^{1/3}$$



Density Functional Theory

In density functional theory, we are going to solve for the shape of the pseudo-potential and the pseudo-wave functions self consistently. That is, we alternate between the potential, which gives the wave functions through Schrödinger's equation, which then give the charge density, which then defines the new potential through Poisson's equation.

There are two approaches to this: (1) real space, and (2) momentum space. In each case, we have to make some approximation to the exchange and correlation energies for the electrons.



	Density Functional Theory	
Real space approaches	Atomic wave functions Pseudo-potential in real space	
	SIESTA, FIREBALL	



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	VASP, QUANTUM ESPRESSO	







Theoretical Methods – Energy Spectrum

- DFT underestimates excitation energies for πconjugated systems.
- Further underestimation in systems where considerable charge transfer occurs.
- Electron correlations in bond dissociation calculations inadequate.
- In general, Hartree-Fock calculations better for interatomic bond distances.





Background — Experimental Results



- AFM tip lowered onto SAM on Au substrate forming nanowire. Stretch begins.
- Photodiode measures deflection of cantilever arm (force). Conductance measured simultaneously.
- Over many repetitions, method can be used to isolate conductance of individual molecules.
- Data gathered from point of contact (Au wire) through molecular bridge until wire breaks.
- Fluctuations at each plateau reveal interesting conductance behavior of stretched molecule.





Organic- Metal Interface

EF

- Schottky-Mott interface model doesn't work
- Charge transfer across interface causes vacuum level shift, Δ .
- UPS used to determine shift photoemission cutoff gives Δ .
- Measure K.E.'s closer to photon energy to get Fermi energy and HOMO, LUMO levels to get φ_h .
- Extent of charge transfer vs. effect on metal surface dipole.











• Contacts separated gradually at each simulation step, allowing nuclei to relax in new position for new Hamiltonian calculation

• Sulfur-pivot carbon-paracarbon angle (S-C-C), ortho-para-orthocarbon angle (para-C) tracked. Gold atoms kept static.





Example of DFT band structure for MoS₂, a transition metal dichalcogenide monolayer





These materials also have the hexagonal form of the Brillouin zone, with minima at the K, K' points.



These are the T valleys of the conduction band. These are the lowest CB valley in bulk, and down to about 2 layers. In the monolayer, the K, K' valleys are the lowest.



One interesting aspect of the TMDCs is the fact that the spin-orbit interaction is oppositely directed in the two valleys of the conduction or valence bands. This gives interesting spin-valley coupling and can produce an effect like the spin Hall effect.





Density Functional Theory

So, we find that DFT is *first principles* band theory.

But, it is very compute intensive, taking perhaps days to reach convergence, the choice for the exchange and correlation potential is varied and using one is hard. Even then the results *may not match what we know from experiment*.



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Wait, I am a practical person (engineer) and I just want to know the shape of the bands. After all, the gaps should match what has been measured for years...



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Empirical Methods

Empirical means forget all that first principles stuff; we are going to use experimental data (data always has all the exchange, correlation, and many-body stuff included, even if I don't recognize it).

We now adjust the values of wave function overlap integrals between adjacent atoms (real space) or the Fourier coefficients of the pseudo-potential (momentum space) to fit the observed energies for the band structure.



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Well, there appears to be some interest locally in the alloys AlAsSb and InAlAs...

Calibration/Test structures

- Intrinsic and p-type <u>AIAsSb</u> for TD PL, TD Hall, XRD, TD Reflectivity, and TD Raman
- Intrinsic and n-type <u>AlInAs</u> for TD PL, TD Hall, XRD, TD Reflectivity, and TD Raman



GaSb, InAs (buffer and substrate), and full structures (T673) will also be compared by Photoluminescence, Raman, XRD, and Reflectivity











Constant energy contour for the top heavy and light hole bands, projected onto the (001) plane









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